查询SN75172N供应商

捷多邦,专业PCB打样工厂,24小时加急出货 SN75172 QUADRUPLE DIFFRENTIAL LINE DRIVER

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- Meets or Exceeds the Requirements of ANSI Standards EIA/TIA-422-B and RS-485 and ITU Recommendation V.11
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- 3-State Outputs
- Common-Mode Output Voltage Range of –7 V to 12 V
- Active-High and Active-Low Enables
- Thermal Shutdown Protection
- Positive- and Negative-Current Limiting
- Operates From Single 5-V Supply
- Logically Interchangeable With AM26LS31

description

The SN75172 is a monolithic quadruple differential line driver with 3-state outputs. It is designed to meet the requirements of ANSI Standards EIA/TIA-422-B and RS-485 and ITU Recommendation V.11. The device is optimized for balanced multipoint bus transmission at rates of up to 4 megabaud. Each driver features wide positive and negative common-mode output voltage ranges, making it suitable for party-line applications in noisy environments.

| N PACKAGE (TOP VIEW) | | | | | |
|--|---|--|--|--|--|
| 1A [1Y [1Z [2Z [2Y [2A [GND [| 1 2 3 4 5 6 7 8 | 16 15 14 13 12 11 10 9 | V _{CC} 4A 4Y 4Z G 3Z 3Y 3A | | |
| D | W PAC (TOP V | KAGI IEW) | | | |
| 1A [1Y [NC [1Z [G [2Z [NC [2Y [2A [GND] | 1 2 3 4 5 6 7 8 9 10 | 20 19 18 17 16 15 14 13 12 11 | V _{CC} 4A 4Y NC 4Z G 3Z NC 3Y 3A | | |

NC – No internal connection

The SN75172 provides positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. Shutdown occurs at a junction temperature of approximately 150°C. This device offers optimum performance when used with the SN75173 or SN75175 quadruple differential line receivers.

The SN75172 is characterized for operation from 0°C to 70°C.

| FUNCTION TABLE (each driver) | | | | | | |
|---------------------------------|-----|------|---------|---|--|--|
| INPUT | ENA | BLES | OUTPUTS | | | |
| Α | G G | | Y | Z | | |
| Н | Н | Х | Н | L | | |
| L | Н | Х | L | Н | | |
| Н | Х | L | Н | L | | |
| L | Х | L | L | н | | |
| Х | S.L | Н | Z | Z | | |



H = high level, L = low level, X = irrelevant, Z = high impedance (off)



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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Terminal numbers shown are for the N package.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature (unless otherwise noted)[‡]

| Supply voltage, V _{CC} (see Note 1) | |
|--|--------------------------------------|
| Voltage range at any bus terminal | $\ldots \ldots \ldots -10$ V to 15 V |
| Input voltage, V _I | 5.5 V |
| Continuous total dissipation | See Dissipation Rating Table |
| Operating free-air temperature range, T _A | \ldots 0°C to 70°C |
| Storage temperature range, T _{stg} | 65°C to 150°C |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C |

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to the network ground terminal.

| DISSIPATION RATING TABLE | | | | | | | |
|--------------------------|------------------------------------|--|---------------------------------------|--|--|--|--|
| PACKAGE | $T_A \le 25^{\circ}C$ POWER RATING | DERATING FACTOR ABOVE T _A = 25°C | T _A = 70°C POWER RATING | | | | |
| DW | 1125 mW | 9.0 mW/°C | 720 mW | | | | |
| N | 1150 mW | 9.2 mW/°C | 736 mW | | | | |



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recommended operating conditions

| | MIN | NOM | MAX | UNIT |
|--|------|----------|------|------|
| Supply voltage, V _{CC} | 4.75 | 5 | 5.25 | V |
| High-level input voltage, VIH | 2 | | | V |
| Low-level input voltage, VIL | | | 0.8 | V |
| Common-mode output voltage, V _{OC} | | -7 to 12 | | V |
| High-level output current, I _{OH} | | | -60 | mA |
| Low-level output current, IOL | | | 60 | mA |
| Operating free-air temperature, T _A | 0 | | 70 | °C |

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | | | TYP† | MAX | UNIT |
|-------------------|---|---------------------------------|--------------------------|--------------------------|---|------|-----------|------|
| VIK | Input clamp voltage | lı = – 18 mA | | | | | -1.5 | V |
| Vo | Output voltage | IO = 0 | | | 0 | | 6 | V |
| VOH | High-level output voltage | V _{IH} = 2 V, | V _{IL} = 0.8 V, | I _{OH} = -33 mA | | 3.7 | | V |
| VOL | Low-level output voltage | V _{IH} = 2 V, | V _{IL} = 0.8 V, | I _{OH} = 33 mA | | 1.1 | | V |
| IVOD1 | Differential output voltage | IO = 0 | | | 1.5 | | 6 | V |
| IVOD2 | Differential output voltage | R _L = 100 Ω, | See Figure 1 | | 1/2 V _{OD1} or 2 [‡] | | | V |
| | | R _L = 54 Ω, | See Figure 1 | | 1.5 | 2.5 | 5 | V |
| V _{OD3} | Differential output voltage | See Note 2 | | | 1.5 | | 5 | V |
| $\Delta V_{OD} $ | Change in magnitude of differential output voltage§ | | | | | | ±0.2 | V |
| Voc | Common-mode output voltage¶ | $R_L = 54 \Omega \text{ or } 1$ | 00 Ω, | See Figure 1 | | | +3 - 1 | V |
| | Change in magnitude of common-mode output voltage§ | | | | | | ±0.2 | V |
| lo | Output current with power off | $V_{CC} = 0,$ | $V_{O} = -7 V$ to 12 V | | | | ±100 | μA |
| loz | High-impedance-state output current | $V_{O} = -7 V$ to T | 12 V | | | | ±100 | μΑ |
| Чн | High-level input current | V _I = 2.7 V | | | | | 20 | μA |
| ۱ _{IL} | Low-level input current | V _I = 0.5 V | | | | | -360 | μA |
| | | $V_{O} = -7 V$ | | | | | -180 | |
| los | Short-circuit output current | $V_{O} = V_{CC}$ | | | | | 180 | mA |
| | | V _O = 12 V | | | | | 500 | |
| | Supply current (all drivers) | No load | Outputs enabled | | | 38 | 60 | mA |
| | | 10000 | Outputs disabled | | | 18 | 40 | |

[†] All typical values are at V_{CC} = 5 V and T_A = 25°C. [‡] The minimum V_{OD2} with a 100- Ω load is either 1/2 V_{OD1} or 2 V, whichever is greater.

¶ In ANSI Standard EIA/TIA-422-B, VOC, which is the average of the two output voltages with respect to ground, is called output offset voltage, V_{OS}. NOTE 2: See Figure 3-5 of EIA Standard RS-485.



 $[\]Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low level.

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| SYMBOL EQUIVALENTS | | | | | | |
|----------------------|---|---|--|--|--|--|
| DATA SHEET PARAMETER | EIA/TIA-422-B | RS-485 | | | | |
| Vo | V _{oa} , V _{ob} | V _{oa} , V _{ob} | | | | |
| IVOD1 | Vo | Vo | | | | |
| IV _{OD2} I | V _t (R _L = 100 Ω) | V _t (R _L = 54 Ω) | | | | |
| IVod2I | | V _t (Test Termination) Measurement 2) | | | | |
| | $ V_t - \overline{V}_t $ | $ V_t - \overline{V}_t $ | | | | |
| VOC | V _{OS} | V _{OS} | | | | |
| | $ V_{OS} - \overline{V}_{OS} $ | $ V_{OS} - \overline{V}_{OS} $ | | | | |
| IOS | _{sa} , I _{sb} | | | | | |
| lo | I _{xa} , I _{xb} | l _{ia} ,l _{ib} | | | | |

switching characteristics, V_{CC} = 5 V, T_A = 25°C

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|--------------------|-------------------------------------|-------------------------|--------------|-----|-----|-----|------|
| ^t d(OD) | Differential-output delay time | D: 54.0 | See Figure 2 | | 45 | 65 | ns |
| tt(OD) | Differential-output transition time | KL = 54 32, | | | 80 | 120 | ns |
| ^t PZH | Output enable time to high level | R _L = 110 Ω, | See Figure 3 | | 80 | 120 | ns |
| t _{PZL} | Output enable time to low level | R _L = 110 Ω, | See Figure 4 | | 45 | 80 | ns |
| ^t PHZ | Output disable time from high level | R _L = 110 Ω, | See Figure 3 | | 78 | 115 | ns |
| t _{PLZ} | Output disable time from low level | R _L = 110 Ω, | See Figure 4 | | 18 | 30 | ns |

PARAMETER MEASUREMENT INFORMATION



Figure 1. Differential and Common-Mode Output Voltages



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $t_f \le 5$ ns, $t_f \le 5$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_O = 50 \Omega$.
 - B. C_L includes probe and stray capacitance.

Figure 2. Differential-Output Test Clrcuit and Voltage Waveforms



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- NOTES. A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, t_f \leq 5 ns, t_f \leq 5 ns, Z_O = 50 Ω .
 - B. CL includes probe and stray capacitance.
 - C. To test the active-low enable G, ground G and apply an inverted waveform to G.

Figure 3. Test Circuit and Voltage Waveforms



- NOTES. A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, t_f \leq 5 ns, t_f \leq 5 ns, Z_O = 50 Ω .
 - B. CL includes probe and stray capacitance.
 - C. To test the active-low enable \overline{G} , ground G and apply an inverted waveform to \overline{G} .

Figure 4. Test Circuit and Voltage Waveforms



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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

APPLICATION INFORMATION



NOTE A: The line length should be terminated at both ends in its characteristic impedance (R_T = Z_O). Stub lengths off the main line should be kept as short as possible.

Figure 11



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